Regarding the change of names mentioned in the document, such as Mitsubishi Electric and Mitsubishi XX, to Renesas Technology Corp.

The semiconductor operations of Hitachi and Mitsubishi Electric were transferred to Renesas Technology Corporation on April 1st 2003. These operations include microcomputer, logic, analog and discrete devices, and memory chips other than DRAMs (flash memory, SRAMs etc.) Accordingly, although Mitsubishi Electric, Mitsubishi Electric Corporation, Mitsubishi Semiconductors, and other Mitsubishi brand names are mentioned in the document, these names have in fact all been changed to Renesas Technology Corp. Thank you for your understanding. Except for our corporate trademark, logo and corporate statement, no changes whatsoever have been made to the contents of the document, and these changes do not constitute any alteration to the contents of the document itself.

Note: Mitsubishi Electric will continue the business operations of high frequency & optical devices and power devices.

Renesas Technology Corp. Customer Support Dept. April 1, 2003





16-BIT CMOS MICROCOMPUTER

DESCRIPTION

These are single-chip 16-bit microcomputers designed with high-performance CMOS silicon gate technology, including the internal flash memory and, being packaged in 64-pin plastic molded QFP or shrink plastic molded DIP. These microcomputers support the 7900 Series instruction set, which are enhanced and expanded instruction set and are upper-compatible with the 7700/7751 Series instruction set. The CPU of these microcomputers is a 16-bit parallel processor that can also be switched to perform 8-bit parallel processing. Also, the bus interface unit of these microcomputers enhances the memory access efficiency to execute instructions fast. Therefore, these microcomputers are suitable for office, business, and industrial equipment controller that require high-speed processing of large data.

For the internal flash memory, single-power-supply programming and erasure, using a PROM programmer or the control by the central processing unit (CPU), is supported. Also, each of these microcomputers has the memory area dedicated for storing a certain software which controls programming and erasure (reprogramming control software). Therefore, on these microcomputers, the program

can easily be changed even after they are mounted on the board.

Also, they are suitable for motor-control equipment since each of

DISTINCTIVE FEATURES

them includes the motor control circuit.

<Microcomputer mode>

<iri>Microcomputer mode></iri>
• Number of basic machine instructions
Memory
Flash memory (User ROM area) 60 Kbytes
RAM3072 bytes
Flash memory (Boot ROM area) 8 Kbytes
 ■ Instruction execution time
The fastest instruction at 20 MHz frequency 50 ns
• Single power supply 5 V ± 0.5 V
• Interrupts 8 external sources, 23 internal sources, 7 levels
● Multi-functional 16-bit timer
(Three-phase motor drive waveform or Pulse motor drive waveform
output is available.)
• Serial I/O (UART or Clock synchronous)
● 10-bit A-D converter 12-channel inputs
● 8-bit D-A converter2-channel outputs
● 12-bit watchdog timer
● Programmable input/output (ports P1, P2, P4, P5, P6, P7, P8) 50

<Flash memory mode>

Power supply voltage	5 V ± 0.5 V
Programming/Erase voltage	5 V ± 0.5 V
Programming method	Programming in a unit of word
Erase method	Block erase or Total erase
M37905F8CFP, M37905F8CSP	
4 blocks (8 Kbytes X 2	, 16 Kbytes X 1, 28 Kbytes X 1)
 Programming/Erase control by soft 	tware command

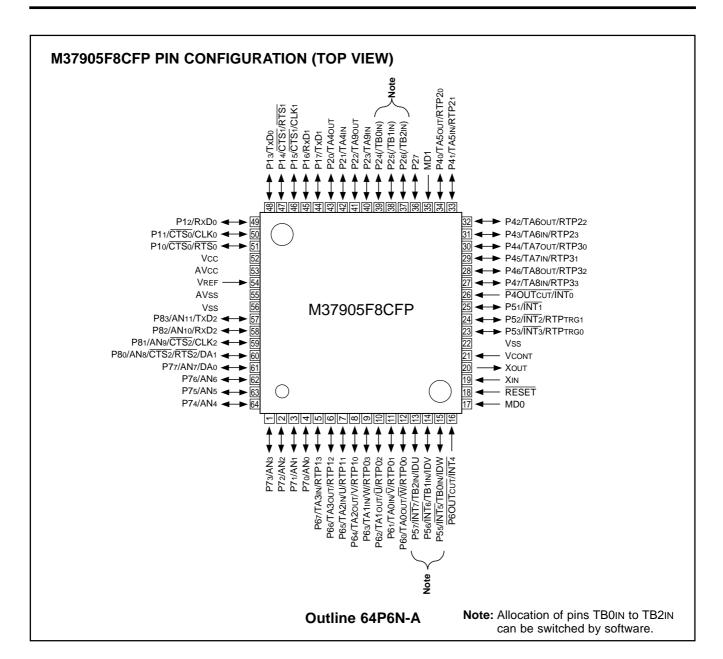
APPLICATION

• Control devices for office equipment such as copiers and facsimiles

- Control devices for industrial equipment such as communication and measuring instruments
- Control devices for equipment, requiring motor control, such as inverter air conditioners and general-purpose inverters

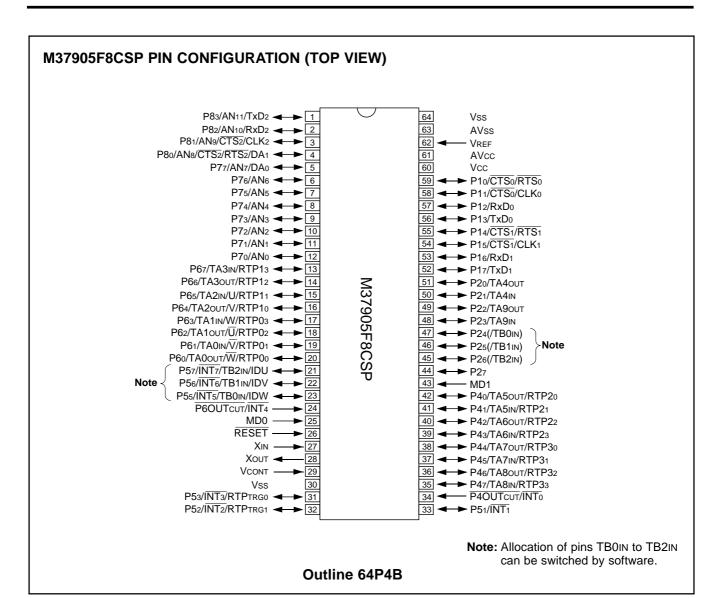






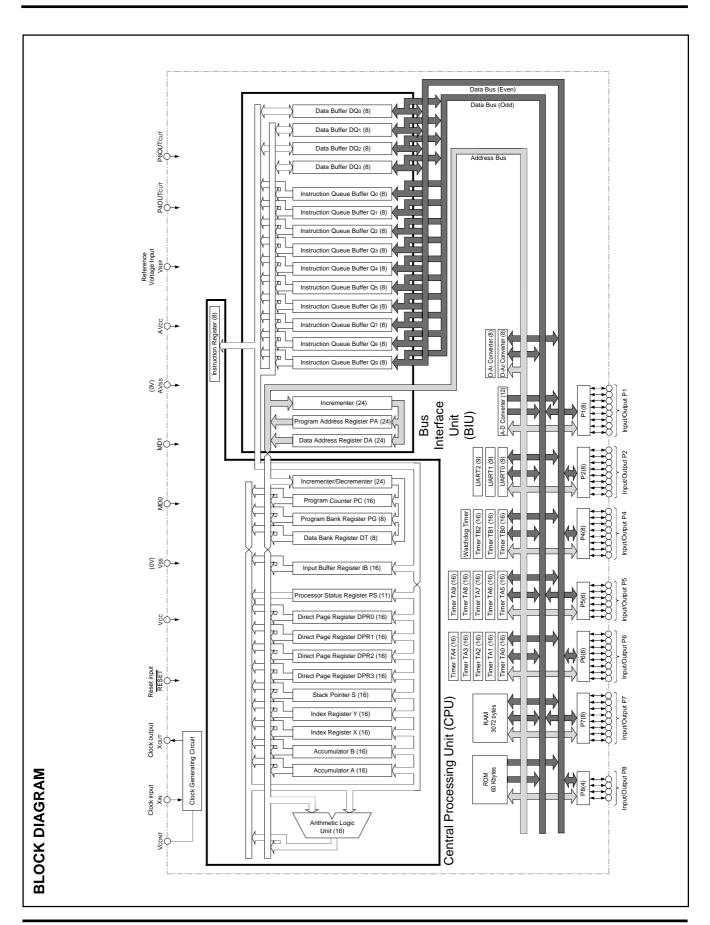


16-BIT CMOS MICROCOMPUTER



Renesas Technology Corp.







16-BIT CMOS MICROCOMPUTER

FUNCTIONS (Microcomputer mode)

	Parameter	Functions		
Number of basic machine instructions		203		
Instruction execution time		50 ns (the fastest instruction at f(fsys) = 20 MHz)		
External clock input frequency for	(XIN)	20 MHz (Max.)		
System clock frequency f(fsys)		20 MHz (Max.)		
Memory size	Flash memory (User ROM area)	60 Kbytes		
	RAM	3072 bytes		
	Flash memory (Boot ROM area)	8 Kbytes		
Programmable input/output	P1, P2, P4, P6, P7	8-bit x 5		
ports	P5	6-bit X 1		
	P8	4-bit X 1		
Multi-functional timers	TA0-TA9	16-bit X 10		
	TB0-TB2	16-bit X 3		
Serial I/O	UART0, UART1, and UART2	(UART or Clock synchronous serial I/O) X 3		
A-D converter		10-bit successive approximation method X 1 (12 channels)		
D-A converter		8-bit X 2		
Dead-time timer		8-bit X 3		
Watchdog timer		12-bit X 1		
Interrupts	Maskable interrups	8 external sources, 20 internal sources. Each interrupt can be set to a priority level within the range of 0–7 by software.		
	Non-maskable interrups	3 internal sources.		
Clock generating circuit		Incorporated (externally connected to a ceramic resonator or quartz crystal resonator).		
PLL frequency multiplier		The following multiplication ratios are available: X2, X3, X4.		
Power supply voltage		5 V±0.5 V		
Power dissipation		125 mW (at f(fsys) = 20 MHz, Typ., ; the PLL frequency multiplier is inactive.)		
Ports' input/output	Input/Output withstand voltage	5 V		
characteristics	Output current	5 mA		
Memory expansion		Not available (single-chip mode only).		
Operating ambient temperature	range	−20 to 85 °C		
Device structure		CMOS high-performance silicon gate process		
Package		(Note)		

Note:	

Packages	M37905F8CFP	64-pin plastic molded QFP (64P6N-A)		
	M37905F8CSP	64-pin shrink plastic moldeds DIP (64P4B)		





16-BIT CMOS MICROCOMPUTER

FUNCTIONS (Flash memory mode)

Parameter		Functions		
Power supply voltage		5 V±0.5 V		
Programming/Erase voltage		5 V±0.5 V		
Flash memory mode		3 modes: parallel I/O, serial I/O, and CPU reprogramming modes		
Block division for erasure	User ROM area	4 blocks (8 Kbytes X 2, 16 Kbytes X 1, 28 Kbytes X 1); total of 60 Kbytes		
	Boot ROM area	1 block (8 Kbytes X 1) (Note)		
Programming method		Programmed per word		
	Flash memory parallel I/O mode	User ROM area + Boot ROM area		
	Flash memory serial I/O mode	User ROM area		
Flash memory CPU reprogramming mode		User ROM area		
Erase method		Total erase/Block erase		
	Flash memory parallel I/O mode	User ROM area + Boot ROM area		
	Flash memory serial I/O mode	User ROM area		
	Flash memory CPU reprogramming mode	User ROM area		
Programming/Erase control		Programming/Erase control by software commands		
Number of commands		6 commands		
Maximum number of reprograms		100		

Note: On shipment, our reprogramming control firmware for the flash memory serial I/O mode has been stored into the boot ROM area.





16-BIT CMOS MICROCOMPUTER

PIN DESCRIPTION (MICROCOMPUTER MODE)

Pin	Name	Input/ Output	Functions
Vcc, Vss	Power supply input	_	Apply 5 V±0.5 V to Vcc, and 0 V to Vss.
MD0	MD0	Input	Connect this pin to Vss.
MD1	MD1	Input	Connect this pin to Vss.
RESET	Reset input	Input	The microcomputer is reset when "L" level is applies to this pin.
XIN	Clock input	Input	These are input and output pins of the internal clock generating circuit. Connect a
Хоит	Clock output	Output	ceramic resonator or quartz-crystal oscillator between pins XIN and XOUT. When an external clock is used, the clock source should be connected to pin XIN, and pin XOUT should be left open.
VCONT	Filter circuit connection	_	When using the PLL frequency multiplier, connect this pin to the filter circuit. When not using the PLL frequency multiplier, this pin should be left open.
AVcc, AVss	Analog power supply input	_	Power supply input pins for the A-D and D-A converters. Connect AVcc to Vcc, and AVss to Vss externally.
VREF	Reference voltage input	Input	This is the reference voltage input pin for the A-D and D-A converters.
P10-P17	I/O port P1	I/O	Port P1 is an 8-bit I/O port. This port has an I/O direction register, and each pin can be programmed for input or output. These pins enter the input mode ar reset. These pins also function as I/O pins of UARTO, 1.
P20-P27	I/O port P2	I/O	In addition to having the same functions as port P1, these pins function as I/O pins for timers A4 and A9. Also, they can be programmed to function as input pins for timers B0 to B2.
P40-P47	I/O port P4	I/O	In addition to having the same functions as port P1, these pins function as I/O pins for timers A5 to A8. Also, they function as output pins for motor drive waveform.
P51–P53, P55–P57	I/O port P5	I/O	In addition to having the same functions as port P1, these pins function as input pins for INT1 to INT3 and INT5 to INT7. Also, pins P55 to P57 function as input pins for timers B0 to B2 and as input pins for position data in the three-phase waveform mode; and pins P52 and P53 function as trigger-input pins in the pulse output port mode.
P60-P67	I/O port P6	I/O	In addition to having the same functions as port P1, these pins function as I/O pins for timers A0 to A3. Also, they function as motor drive waveform output pins.
P70-P77	I/O port P7	I/O	In addition to having the same functions as port P1, these pins function as input pins for the A-D converter. Also, P77 functions as an output pin for the D-A converter.
P80-P83	I/O port P8	I/O	In addition to having the same functions as port P1, these pins function as input pins for the A-D converter. Also, these pins function as I/O pins for UART2, and pin P80 functions as an output pin for the D-A converter.
P4OUTcut	P4OUTcuT input	Input	This pin has the function to forcibly place port P4 pins in the input mode. Also, this pin functions as an input pin for INTo; and this pin is used to input a signal, which forcibly cuts off a motor drive waveform output.
P6OUTcut	P6OUTcuT input	Input	This pin has the function to forci <u>bly place</u> port P6 pins in the input mode. Also, this pin functions as an input pin for INT4; and this pin is used to input a signal, which forcibly cuts off a motor drive waveform output.





16-BIT CMOS MICROCOMPUTER

PIN DESCRIPTION (FLASH MEMORY SERIAL I/O MODE)

Pin	Name	Input /Output	Functions
Vcc, Vss	Power supply input	_	Apply 5 V ± 0.5 V to Vcc, and 0 V to Vss.
MD0	MD0	Input	Connect this pin to Vss.
MD1	MD1	Input	Connect this pin to Vss via a resistor of 10 k Ω to 100 k Ω .
RESET	Reset input	Input	The reset input pin.
XIN	Clock input	Input	Connect a ceramic oscillator between the XIN and XOUT pins, or input an external
Xout	Clock output	Output	clock from the XIN pin with the XOUT pin left open.
AVcc, AVss	Analog supply input	_	Connect AVcc to Vcc, and AVss to Vss.
VREF	Reference voltage input	Input	Input an arbitrary level within the range of VSS–VCC. (This is not used in the flash memory serial I/O mode.)
P10-P17	Input port P1	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
P20-P23, P27	Input port P2	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
P24	SCLK input	Input	This is an input pin for a serial clock.
P25	SDA I/O	I/O	This is an I/O pin for serial data. Connect this pin to Vcc via a resistor (about 1 kΩ).
P26	BUSY output	Output	This is an output pin for the BUSY signal.
P4OUTcut	P4OUTCUT input	Input	Input "H".
P6OUTcut	P60UTcut input	Input	Input "H".
P40-P47	Input port P4	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
P55-P53,	Input port P5	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
P55-P57			
P60-P67	Input port P6	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
P70-P74	Input port P7	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
P80-P83	Input port P8	Input	Input "H" or "L", or leave them open. (This is not used in the flash memory serial I/O mode.)
VCONT	Filter circuit connection	_	Connect this pin to the filter circuit, or leave this pin open. (This is not used in the flash memory serial I/O mode.)







BASIC FUNCTION BLOCKS

Each of the M37905F8CFP and M37905F8CSP has the same function as that of the M37905M4C-XXXFP except for the following. Therefore, for details except for the following, refer to the datasheet of the M37905M4C-XXXFP.

- Internal ROM: type (flash memory) and size
- RAM size

MEMORY

Figure 1 shows the memory map.

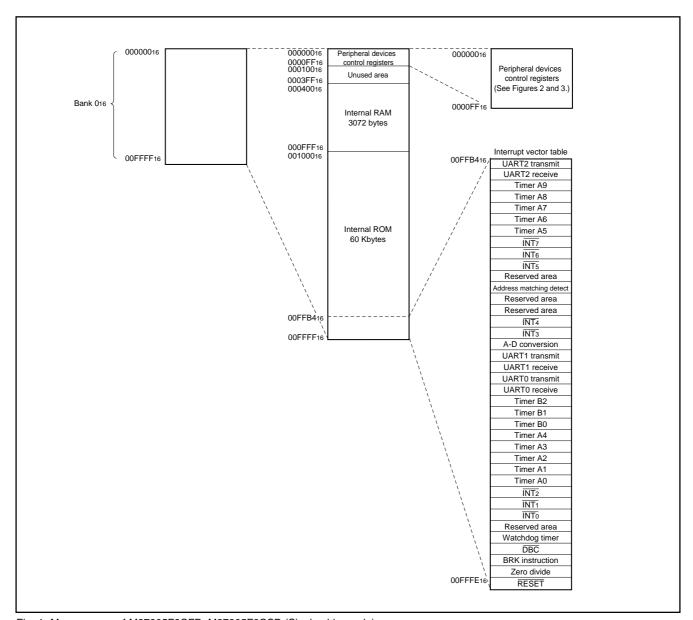


Fig. 1 Memory map of M37905F8CFP, M37905F8CSP (Single-chip mode)



16-BIT CMOS MICROCOMPUTER

00000016	Reserved area (Note)	00004016	Count start register 0
00000116	Reserved area (Note)	00004116	
00000216	Reserved area (Note)	00004216	·
00000316	Port P1 register	00004316	One-shot start register 1
00000416	Reserved area (Note)	00004416	Up-down register 0
00000516	Port P1 direction register	00004516	Timer A clock division select register
00000616	Port P2 register	00004616	·
00000716	Reserved area (Note)	00004716	Timer A0 register
00000816	Port P2 direction register	00004816	
00000916	Reserved area (Note)	00004916	Timer A1 register
00000A16	Port P4 register	00004A16	T: 40 : (
00000B16	Port P5 register	00004B16	Timer A2 register
00000C16	Port P4 direction register	00004C16	T: 40 : (
00000D16	Port P5 direction register	00004D16	Timer A3 register
00000E16	Port P6 register	00004E16	T: A4 :
00000F16	Port P7 register	00004F16	Timer A4 register
00001016	Port P6 direction register	00005016	T: D0 : (
00001116	Port P7 direction register	00005116	Timer B0 register
00001116	Port P8 register	00005216	T. D4
00001316		00005316	Timer B1 register
00001416	Port P8 direction register	00005416	T: DO : .
00001516	J	00005516	Timer B2 register
00001616	Reserved area (Note)	00005616	Timer A0 mode register
00001716	Reserved area (Note)	00005716	
00001816	Reserved area (Note)	00005816	3
00001916	Reserved area (Note)	00005916	Timer A3 mode register
00001A16	, ,	00005A16	Timer A4 mode register
00001B16		00005B16	Ü
00001C16		00005C16	
00001D16		00005D16	Ü
00001E16	A-D control register 0	00005E16	Processor mode register 0
00001F16	A-D control register 1	00005F16	<u> </u>
00002016	·	00006016	Watchdog timer register
00002116	A-D register 0	00006116	
00002216		00006216	Particular function select register 0
00002316	A-D register 1	00006316	Particular function select register 1
00002416		00006416	Particular function select register 2
00002516	A-D register 2	00006516	Reserved area (Note)
00002616		00006616	Debug control register 0
00002716	A-D register 3	00006716	Debug control register 1
00002816	A.B	00006816	
00002916	A-D register 4	00006916	Address comparison register 0
00002A16		00006A16	The state of the s
00002B16	A-D register 5	00006B16	
00002C16		00006C16	Address comparison register 1
00002D16	A-D register 6	00006D16	
00002E16		00006E16	INT3 interrupt control register
00002F16	A-D register 7	00006F16	INT4 interrupt control register
00003016	UART0 transmit/receive mode register	00007016	A-D conversion interrupt control register
00003116	UART0 band rate register (BRG0)	00007116	UART0 transmit interrupt control register
00003216	<u> </u>	00007716	
00003216	UART0 transmit buffer register	00007216	
00003416	UART0 transmit/receive control register 0	00007416	1 0
00003516	UART0 transmit/receive control register 1	00007116	
00003616		00007616	Timer A1 interrupt control register
00003716	UART0 receive buffer register	00007716	, ,
00003716	UART1 transmit/receive mode register	00007716	
00003016	UART1 baud rate register (BRG1)	00007916	3
00003316 00003A16	<u> </u>	00007916 00007A16	Timer B0 interrupt control register
00003A16	UART1 transmit buffer register	00007A16	Timer B1 interrupt control register
00003D16	UART1 transmit/receive control register 0	00007B16	, o
00003D16	UART1 transmit/receive control register 1	00007D16	
00003E16		00007E16	
00003E16	UART1 receive buffer register	00007E16	
200031 16		00007 F16	11412 antonupt control register

Fig. 2 Location of SFRs (1)







00008016	Reserved area (Note)	0000C016	
00008116	Reserved area (Note)	0000C116	
00008216	Reserved area (Note)	0000C216	
00008316	Reserved area (Note)	0000C316	
00008416	Reserved area (Note)	0000C416	Up-down register 1
00008516	Reserved area (Note)	0000C516	•
00008616	Reserved area (Note)	0000C616	T: A5 ::
00008716	Reserved area (Note)	0000C716	Timer A5 register
00008816		0000C816	- : 40
00008916		0000C916	Timer A6 register
00008A16	Reserved area (Note)	0000CA16	Timer A7 register
00008B16		0000CB16	Timer A7 register
00008C16	Reserved area (Note)	0000CC16	Timer A8 register
00008D16		0000CD16	Time 7 to regioter
00008E16	Reserved area (Note)	0000CE16	Timer A9 register
00008F16	Decembed and (Nets)	0000CF16	- Time: 7 to regiote:
00009016	Reserved area (Note)	0000D016	Timer A01 register
00009116	D 1 (N.4.)	0000D116	
00009216	Reserved area (Note)	0000D216	Timer A11 register
00009316		0000D316	-9
00009416 00009516	External interrupt input road out register	0000D416	Timer A21 register
	External interrupt input read-out register	0000D516	
00009616 00009716	D-A control register	0000D616 0000D716	Timer A5 mode register
00009716	D-A register 0	0000D716 0000D816	Timer A6 mode register Timer A7 mode register
00009816	D-A register 0	0000D816	Timer A7 mode register Timer A8 mode register
00009916 00009A16	D-A legister i	0000D916	Timer A9 mode register
00009A16		0000DA16	A-D control register 2
00009C16	Reserved area (Note)	0000DD16	Comparator function select register 0
00009D16	Reserved area (Note)	0000DD16	Comparator function select register 1
00000E16	Flash memory control register	0000DE16	Comparator result register 0
00009F16	, , , , , , , , , , , , , , , , , , , ,	0000DF16	Comparator result register 1
0000A016	Pulse output control register	0000E016	-
0000A116	, , , , , , , , , , , , , , , , , , ,	0000E116	A-D register 8
0000A216	Pulse output data register 0	0000E216	A.B
0000A316	, ,	0000E316	A-D register 9
0000A416	Pulse output data register 1	0000E416	A.D. register 40
0000A516		0000E516	A-D register 10
0000A616	Waveform output mode register	0000E616	A-D register 11
0000A716	Dead-time timer	0000E716	A-D legister 11
0000A816	Three-phase output data register 0	0000E816	Reserved area (Note)
0000A916	Three-phase output data register 1	0000E916	Reserved area (Note)
0000AA16	Position-data-retain function control register	0000EA16	Reserved area (Note)
0000AB16		0000EB16	Reserved area (Note)
0000AC16	Serial I/O pin control register	0000EC16	Reserved area (Note)
0000AD16		0000ED16	Reserved area (Note)
0000AE16	Port P2 pin function control register	0000EE16	Reserved area (Note)
0000AF16		0000EF16	Reserved area (Note)
0000B016	3	0000F016	LIADTO to a consisting to the second
0000B116	UART2 band rate register (BRG2)	0000F116	UART2 transmit interrupt control register
0000B216	UART2 transmit buffer register	0000F216	UART2 receive interrupt control register
0000B316	UART2 transmit/receive control register 0	0000F316	
0000B416		0000F416 0000F516	Timer AE interrupt control register
0000B516	UART2 transmit/receive control register 1		Timer A5 interrupt control register
0000B616 0000B716	UART2 receive buffer register	0000F616 0000F716	Timer A6 interrupt control register Timer A7 interrupt control register
	Popurud area (Nata)		Timer A7 Interrupt control register Timer A8 interrupt control register
0000B816 0000B916	Reserved area (Note)	0000F816 0000F916	Timer A9 interrupt control register Timer A9 interrupt control register
0000B916	Reserved area (Note)	0000F916 0000FA16	ninei Aa interrupt control register
0000BA16	Reserved area (Note)	0000FA16 0000FB16	
0000BC16	Clock control register 0	0000FB16	
0000BC16	Reserved area (Note)	0000FC16 0000FD16	INTs interrupt control register
0000BD16	` '	0000FD16 0000FE16	INT6 interrupt control register INT6 interrupt control register
0000BE16	` ,	0000FE16	
2000DI 10	1.000.1700 died (140to)	00001110	1117 Interrupt control register

Fig. 3 Location of SFRs (2)



RELIGION ARY Notice: This is not a final specification. Notice: This is not a final specification. Some parametric limits are subject to change.

MITSUBISHI MICROCOMPUTERS M37905F8CFP, M37905F8CSP

16-BIT CMOS MICROCOMPUTER

FLASH MEMORY MODE

These microcomputers contain the flash memory; and single-powersupply reprogramming is available to this. These microcomputers have the following three modes, enabling reading/programming/erasure for the flash memory:

- Flash memory parallel I/O mode and Flash memory serial I/O mode, where the flash memory is handled by using an external programmer.
- CPU reprogramming mode, where the flash memory is handled by the central processing unit (CPU).

As shown in Figure 4, the flash memory is divided into several blocks, and erasure per block is possible.

This internal flash memory has the boot ROM area storing the reprogramming control software for reprogramming in the CPU reprogramming mode and flash memory serial I/O mode, as well as the user ROM area storing a certain control software for the normal operation in the microcomputer mode.

Although our reprogramming control firmware for the flash memory serial I/O mode has been stored into this boot ROM area on shipment, the user-original reprogramming control software which is more appropriate for the user's system is reprogrammable into this area, instead. Note that the reprogramming for the boot ROM area is enabled only in the flash memory parallel I/O mode.

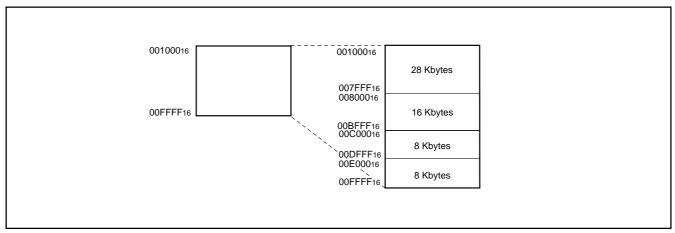


Fig. 4 M37905F8CFP, M37905F8CSP: block configuration of internal flash memory



MITSUBISHI MICROCOMPUTERS



M37905F8CFP, M37905F8CSP

16-BIT CMOS MICROCOMPUTER

Flash Memory Parallel I/O Mode

The flash memory parallel I/O mode is used to manipulate the internal flash memory with a parallel programmer. This parallel programmer uses the software commands listed in Table 1 to do the flash memory manipulations, such as read/programming/erase operations.

Table 1. Software commands (flash memory parallel I/O mode

	Software Command
Read Array	
Read Status Register	
Clear Status Register	
Programming	
Block Erase	
Erase All Block	

Addresses FF9016 to FF9F16 are the reserved area for the parallel programmer. Therefore, when the user uses the flash memory parallel I/O mode, do not program to this area.

User ROM Area and Boot ROM Area

The user ROM area and boot ROM area can be reprogrammed in the flash memory parallel I/O mode.

The programming and block erase operations can be performed only to these areas

The boot ROM area, 8 Kbytes in size, is assigned to addresses 000016–1FFF16, so that programming and block erase operations can be performed only to this area. (Access to any address out of this area is prohibited).

The erasable block in the boot ROM area is only one block, consisting of 8 Kbytes. The reprogramming control firmware to be used in the flash memory serial I/O mode has been stored to this boot ROM area on our shipment. Therefore, do not reprogram the boot ROM area if the user uses the flash memory serial I/O mode.

Do not program to addresses FF9016 to FF9F16 because this area is the reserved area for the programmer.

Note that, when the boot ROM area is read out from the CPU in the CPU reprogramming mode, described later, its addresses will be shifted to E00016—FFFF16.



Notice: This is not a final specification to change. Notice: This is not a final specific to change. Some parametric limits are subject to change.

MITSUBISHI MICROCOMPUTERS M37905F8CFP, M37905F8CSP

16-BIT CMOS MICROCOMPUTER

Flash Memory Serial I/O Mode

In the flash memory serial I/O mode, addresses, data, and software commands, which are required to read/program/erase the internal flash memory, are serially input and output with a fewer pins and the dedicated serial programmer.

In this mode, being different from the flash memory parallel I/O mode, the CPU controls reprogramming of the flash memory (using the CPU reprogramming mode), serial input of the reprogramming data, etc.

The reprogramming control firmware for the flash memory serial I/O mode has been stored in the boot ROM area on shipment of the product from us. Note that, then, the flash memory serial I/O mode will become unavailable if the boot ROM area has been reprogrammed in the flash memory parallel I/O mode.

Note that, also, this reprogramming control firmware for the flash memory serial I/O mode is subject to change.

Figures 5 and 6 show the pin connections in the flash memory serial $\ensuremath{\mathsf{I/O}}$ mode.

The three pins, SCLK, SDA, and BUSY, are used to input and output serial data.

The SCLK pin is the input pin of external transfer clocks. The SDA pin is the I/O pin of transmit and receive data, and its output acts as the N-channel open-drain output. To the SDA pin, connect an external pullup resistor (about 1 k Ω). The BUSY pin is the output pin of the BUSY flag (CMOS output) and goes "H" during BUSY periods owing to a certain operation, such as transmit, receive, erase, programming, etc.

Transmit and receive data are serially transferred 8 bits at a time. In the flash memory serial I/O mode, only the user ROM area can be reprogrammed; the boot ROM area is not accessible.

Addresses FF9016 to FF9F16 are the reserved area for the serial programmer. Therefore, when the user uses the flash memory serial I/O mode, do not program to this area.





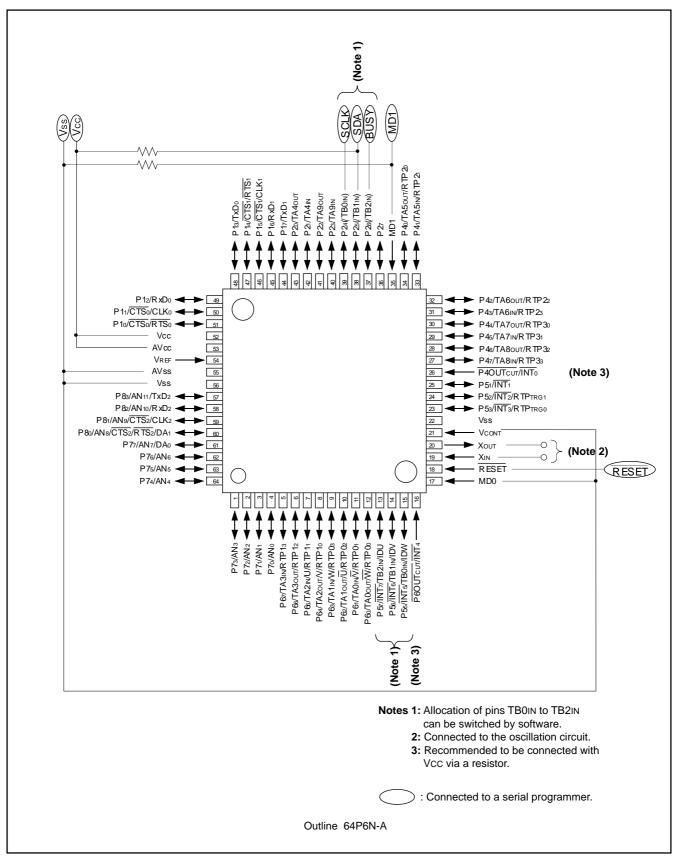


Fig. 5 Pin connection of M37905F8CFP in flash memory serial I/O mode (outline: 64P6N-A)





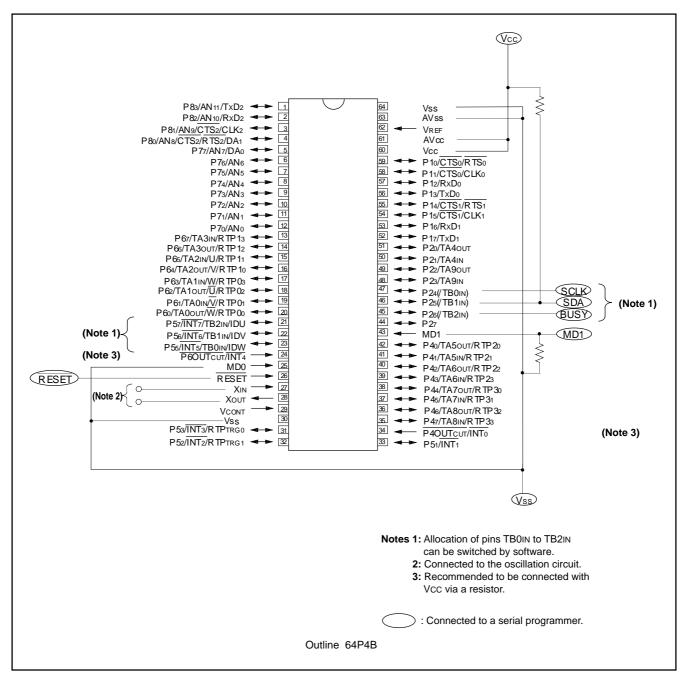


Fig. 6 Pin connection of M37905F8CSP in flash memory serial I/O mode (outline: 64P4B)



16-BIT CMOS MICROCOMPUTER

CPU Reprogramming Mode

The CPU reprogramming mode is used to perform the operations for the internal flash memory (reading, programming, erasing) under control of the CPU.

In this mode, only the user ROM area can be reprogrammed; the boot ROM area cannot be reprogrammed.

The user-original reprogramming control software for the CPU reprogramming mode can be stored in either the user ROM area or the boot ROM area.

Because the CPU cannot read out the flash memory in the CPU reprogramming mode, the above software must be transferred to the internal RAM in advance to be executed.

Boot Mode

The user-original reprogramming control software for the CPU reprogramming mode must be stored into the user ROM area or the boot ROM area in the flash memory parallel I/O mode in advance. (If this program has been stored into the boot ROM area, the flash memory serial I/O mode will become unavailable).

Note that addresses of the boot ROM area depend on the accessing ways to the boot ROM area, When accessing in the flash memory parallel I/O mode, these addresses will be shifted to 000016 to 1FFF16. On the other hand, when accessing with the CPU, these addresses will be shifted to E00016 to FFFF16.

Reset removal with both of the MD0 and MD1 pins held "L" invokes the normal microcomputer mode, and the CPU operates using the control software stored in the user ROM area. In this case, the boot ROM area is not accessible.

Removing reset with the MD0 pin held "L" and the MD1 pin "H", the CPU starts its operation using the reprogramming control software stored in the boot ROM area. This mode is called the boot mode. The reprogramming control software in the boot ROM area can also reprogram the user ROM area.

After reset removal, be sure not to change the status at pins MD0 and MD1

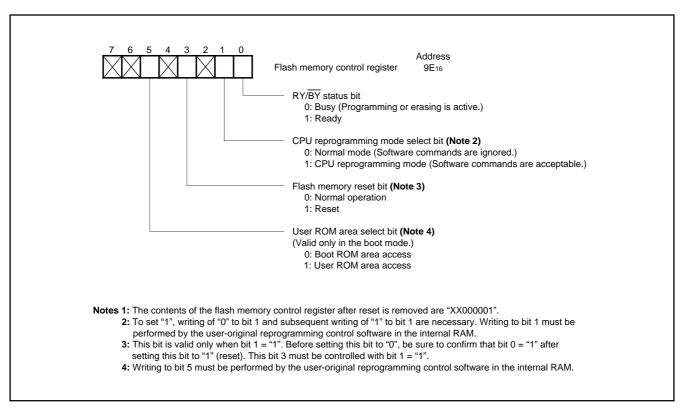


Fig. 7 Bit configuration of flash memory control register

Notice: This is not a final specification thange. Some parametric limits are subject to change.

MITSUBISHI MICROCOMPUTERS M37905F8CFP, M37905F8CSP

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Function overview (CPU reprogramming mode)

The CPU reprogramming mode is available in the single-chip mode, memory expansion mode, and boot mode to reprogram the user ROM area only.

In the CPU reprogramming mode, the CPU erases, programs, and reads the internal flash memory by writing software commands. Note that the user-original reprogramming control software must be transferred to the internal RAM in advance to be executed.

The CPU reprogramming mode becomes active when "1" is written into the flash memory control register's bit 1 (the CPU reprogramming mode select bit) shown in Figure 7, and software commands become acceptable.

In the CPU reprogramming mode, software commands and data are all written to and read from even addresses (Note that address Ao in byte addresses = "0".) 16 bits at a time. Therefore, a software command consisting of 8 bits must be written to an even address; therefore, any command written to an odd address will be invalid. Since the write data at the 2nd cycle of a programming command consists of 16 bits, this data must be written to even and odd addresses.

The seaquencer in the flash memory controls the erase and programming operations. What the status of the seaquencer operation is and whether the programming or erase operation has been completed normally or terminated by an error can be examined by reading the flash memory control register.

Figure 7 shows the bit configuration of the flash memory control register.

Bit 0 (the RY/BY status bit) is a read-only bit for indicating the seaquencer operation. This bit goes to "0" (BUSY) while the automatic programming/erase operation is active and goes to "1" (READY) during the other operations.

Bit 1 serves as the CPU reprogramming mode select bit. Writing of "1" to this bit selects the CPU reprogramming mode, and software commands will be acceptable. Because the CPU cannot directly access the internal flash memory in the CPU reprogramming mode, writing to this bit 1 must be performed by the user-original reprogramming control software which has been transferred to the internal RAM in advance. To set bit 1 to "1", it is necessary to write "0" and "1" to this bit 1 successively. On the other hand, to clear this bit to "0", it is sufficient only to write "0".

Bit 3 (the flash memory reset bit) resets the control circuit of the internal flash memory and is used when the CPU reprogramming mode is terminated or when an abnormal access to the flash memory happens. Writing of "1" to bit 3 with the CPU reprogramming mode select bit = "1" preforms the reset operation. To remove the reset, write "0" to bit 3 after confirming bit 0 (the RY/BY status bit) becomes "1".

Bit 5 serves as the user ROM area select bit and is valid only in the boot mode. Setting this bit to "1" in the boot mode switches an accessible area from the boot ROM area to the user ROM area. To use the CPU reprogramming mode in the boot mode, set this bit to "1". Note that when the microcomputer is booted up in the user ROM area, only the user ROM area is accessible and bit 5 is invalid; on the other hand, when the microcomputer is in the boot mode, bit 5 is valid independent of the CPU reprogramming mode. To rewrite bit 5, execute the user-original reprogramming control software transferred to the internal RAM in advance.

Figure 8 shows the CPU reprogramming mode set/termination flow-

chart, and be sure to follow this flowchart. As shown in Note 1 of Figure 8, before selecting the CPU reprogramming mode, set "0" to the processor mode register 1's bit 7 (the internal ROM bus cycle select bit) and set flag I to "1" to avoid an interrupt request input.

When a watchdog timer interrupt request is generated in the CPU reprogramming mode, when an input to the RESET pin is "L", or when the software reset is performed, the flash memory control circuit and flash memory control register will be reset.

When the flash memory is reset during the erase or programming operation, this operation is cancelled and the target block's data will be invalid. Just before writing a software command related to the erase/programming operation, be sure to write to the watchdog timer. In the CPU reprogramming mode, be sure not to use the **STP** and **WIT** instructions.





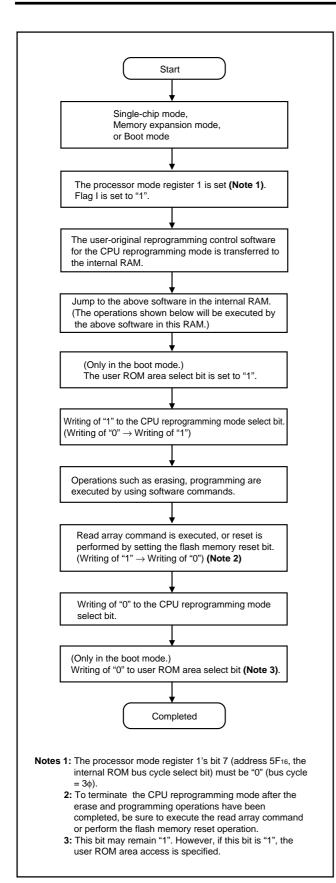


Fig. 8 CPU reprogramming mode set/termination flowchart

Software Commands

Table 2 lists the software commands.

By writing a software command after the CPU reprogramming mode select bit has been set to "1", erasing, programming, etc. can be specified. Note that, at software commands' input, the high-order byte (D8–D15) is ignored. (Except for the write data at the 2nd cycle of a programming command.)

Software commands are explained as below.

Read Array Command (FF16)

By writing command code "FF16" at the 1st bus cycle, the microcomputer enters the read array mode. If an address to be read is input in the next or the following bus cycles, the contents at the specified address are output to the data bus (D0 to D15) in a unit of 16 bits.

The read array mode is maintained until writing of another software command.

Read Status Register Command (7016)

Writing command code "7016" at the 1st bus cycle outputs the contents of the status register to the data bus (D0-D7) by a read at the 2nd bus cycle.

The status register is explained later.

Clear Status Register Command (5016)

This command clears two status bits (SR.4, 5) each of which is set to "1" to indicate that the operation has been terminated by an error. To clear these bits, write command code "5016" at the 1st bus cycle.

Programming Command (4016)

This command facilitates programming of 1 word (2 bytes) at a time. To initiate programming, write command code "4016" at the 1st bus cycle; when write data is written in a unit of 16 bits at the 2nd bus cycle, the address is specified at the same time. Upon completion of data writing, automatic programming (data programming and verification) operation is started.

The completion of the automatic programming operation is confirmed by a read of the flash memory control register. The RY/ $\overline{\text{BY}}$ status bit of the flash memory control register goes "0" during the automatic programming operation; and also, it goes "1" after the end of it.

Before execution of the next command, be sure to confirm that the RY/\overline{BY} status bit is set to "1" (READY). During the automatic programming operation, writing of commands and access to the flash memory must not be performed.

When programming continuously, the programming command can be executed with the read status register mode kept if there is no programming error. Simultaneously with start of the automatic programming, the read status register mode is automatically active. In this case, the read status register mode is retained until the next read array command (FF16) is written or until the reset is performed by using the flash memory reset bit.

Reading out the status register after the automatic programming operation is completed reports the result of it. For details, refer to the section on the status register.

Figure 9 shows an example of the programming flowchart.

Additional programming to any word that has already been programmed is prohibited.







Table 2. Software commands (CPU reprogramming mode)

	1st cycle			2nd cycle		
Command	Mode	Address	Data (D ₀ to D ₇)	Mode	Address	Data
Read Array	Write	X (Note 2)	FF16	_	_	_
Read Status Register	Write	Х	7016	Read	Х	SRD (Note 3)
Clear Status Register	Write	Х	5016	_	_	_
Programming	Write	Х	4016	Write	WA (Note 4)	WD (Note 4)
Block Erase	Write	Х	2016	Write	BA (Note 5)	D016
Erase All Block	Write	Х	2016	Write	Х	2016

Notes 1: At software commands' input, the high-order byte of data (D8-D15) is ignored.

- 2: X = An arbitrary address in the user ROM area. (Note that A0 = "0".)
- 3: SRD = Status Register Data
- 4: WA = Write Address, WD = Write Data (16 bits).
- 5: Block address: the maximum address of each block must be input. Note that address A0 = "0".

Block Erase Command (2016/D016)

Writing command code "2016" at the 1st bus cycle and writing confirmation command code "D016" and the maximum address of the block (Note that address A0 = "0".) at the subsequent 2nd bus cycle initiate the automatic erase (erasing and erase verification) operation for the specified block.

The completion of the automatic erase operation is confirmed by a read of the flash memory control register. The RY/ $\overline{\text{BY}}$ status bit of the flash memory control register goes "0" simultaneously with start of the automatic erase operation; and also, it goes "1" simultaneously with completion of it.

Before execution of the next command, be sure to confirm that the RY/\overline{BY} status bit is set to "1" (READY). During the automatic erase operation, writing of commands and access to the flash memory must not be performed.

Simultaneously with start of the automatic erase, the read status register mode is automatically active. In this case, the read status register mode is retained until the next read array command (FF16) is written or until the reset is performed by using the flash memory reset bit.

Reading out the status register after the automatic erase operation is completed reports the result of it. For details, refer to the section on the status register.

Figure 10 shows an example of the block erase flowchart.





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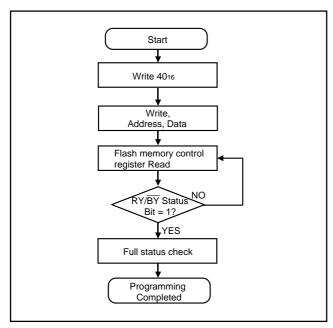


Fig. 9 Programming flowchart

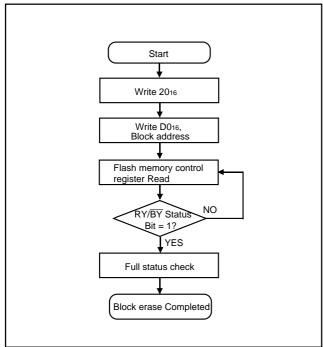


Fig. 10 Block erase flowchart

Erase All Block Command (2016/2016)

Writing command code "2016" at the 1st bus cycle and writing command code "2016" at the subsequent 2nd bus cycle initiate the continuous block erase (chip erase) operations for all the blocks.

The completion of the chip erase operation, as well as of the block erase operation, is confirmed by a read of the flash memory control register. The result of the automatic erase operation is also reported by a read of the status register.

During the automatic erase operation (when the RY/ \overline{BY} status bit = "0"), writing of commands and access to the flash memory must not be performed.

Status Register

The status register is used to indicate whether the programming/ erase operation has been completed normally or terminated by an error. By writing the read status register command (7016), the contents of the status register can be read out; by writing the clear status register command (5016), the contents of the status register can be cleared.

Table 3 lists the definition of each bit of the status register.

The status register outputs "8016" after reset is removed.

The status of each bit is described below.



Notice: This is not a final specification change. Some parametric limits are subject to change.

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Erase Status Bit (SR.5)

This bit reports the status of the automatic erase operation. This bit is set to "1" if an erase error occurs and returns to "0" if the clear status register command (5016) is written.

Programming Status Bit (SR.4)

This bit reports the status of the automatic programming operation. This bit is set to "1" if a programming error occurs and returns to "0" if the clear status register command (5016) is written.

Under the condition that any of SR.5, SR.4 = "1", none of the programming, block erase, and erase all block commands can be accepted. Before execution of these commands, execute the clear status register command (5016), in advance, to clear these status bits.

Both of SR.4, SR.5 are set to "1" under the following conditions (Command Sequence Error):

- (1) when data other than "D016" and "FF16" is written to the data in the 2nd bus cycle of the block erase command (2016/D016)
- (2) when data other than "2016" and "FF16" is written to the data in the 2nd bus cycle of the erase all block command (2016/2016)

Note that, writing of "FF16" forces the microcomputer into the read array mode. Simultaneously with this, the command written in the 1st bus cycle will be canceled.

Full Status Check

The full status check reports the results of the erase or programming operation.

Figure 11 shows the full status check flowchart and actions to be taken if an error has occurred.

Table 3. Bit definition of status register

Course In a I	Status	Definition		
Symbol	Status	"1"	"0"	
SR.7 (D7)	Reserved			
SR.6 (D6)	Reserved		_	
SR.5 (D5)	Erase Status	Terminated by error.	Terminated normally.	
SR.4 (D4)	Programming Status	Terminated by error.	Terminated normally.	
SR.3 (D3)	Reserved		_	
SR.2 (D2)	Reserved			
SR.1 (D1)	Reserved			
SR.0 (D ₀)	Reserved		_	







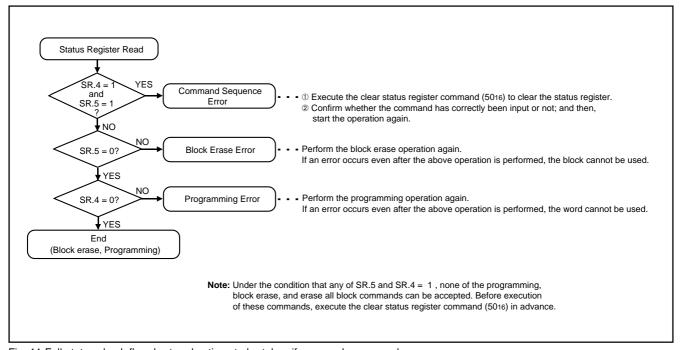


Fig. 11 Full status check flowchart and actions to be taken if an error has ocurred

DC Electrical Characteristics (Vcc = $5 \text{ V} \pm 0.5 \text{ V}$, Ta = 0 to 60 °C, f(fsys) = 20 MHz (Note))

Symbol	Parameter	Limits			l lasia
		Min.	Тур.	Max.	Unit
Icc1	Vcc power source current (at read)		30	48	mA
lcc2	Vcc power source current (at write)			48	mA
Icc3	Vcc power source current (at programming)			54	mA
Icc4	Vcc power source current (at erasing)			54	mA

Limits of VIH, VIL, VOH, VOL, IIH, and IIL for each pin are the same as those in the microcomputer mode.

Note: f(fsys) indicates the system clcok (fsys) frequency.

AC Electrical Characteristics (Vcc = 5 V ± 0.5 V, Ta = 0 to 60 °C, f(fsys) = 20 MHz (Note))

				. ,
Doromotor		1.1:4		
Parameter		Тур.	Max.	Unit
256-byte programming time		4	40	ms
Block erase time		0.6	8	S
Erase all block time		0.6 X n	8 X n	S

n = Number of blocks to be erased

The limits of parameters other than the above are same as those in the microcomputer mode.

Note: f(fsys) indicates the system clock (fsys) frequency.





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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Ratings	Unit
Vcc	Power source voltage	-0.3 to 6.5	V
AVcc	Analog power source voltage	-0.3 to 6.5	V
VI	Input voltage P10–P17, P20–P27, P40–P47, P51–P53, P55–P57, P60–P67, P70–P77, P80–P83, P40UTcuT, P60UTcuT, Vcont, VREF, XIN, RESET, MD0, MD1	-0.3 to Vcc+0.3	V
Vo	Output voltage P10–P17, P20–P27, P40–P47, P51–P53, P55–P57, P60–P67, P70–P77, P80–P83, XOUT	-0.3 to Vcc+0.3	V
Pd	Power dissipation	300	mW
Topr	Operating ambient temperature	-20 to 85	°C
Tstg	Storage temperature	-40 to 150	°C

RECOMMENDED OPERATING CONDITIONS (Vcc = 5 V, Ta = -20 to 85 °C, unless otherwise noted)

Cumbel	Description		Limits		
Symbol	Parameter	Min.	Тур.	Max.	Unit
Vcc	Power source voltage	4.5	5.0	5.5	V
AVcc	Analog power source voltage		Vcc		V
Vss	Power source voltage		0		V
AVss	Analog power source voltage		0		V
VIH	High-level Input voltage P10–P17, P20–P27, P40–P47, P51–P53, P55–P57, P60–P67, P70–P77, P80–P83, P40UTcut, P60UTcut, XIN, RESET, MD0, MD1	0.8 Vcc		Vcc	V
VIL	Low-level Input voltage P10–P17, P20–P27, P40–P47, P51–P53, P55–P57, P60–P67, P70–P77, P80–P83, P40UTcut, P60UTcut, XIN, RESET, MD0, MD1	0		0.2 VCC	V
IOH(peak)	High-level peak output current P10–P17, P20–P27, P55–P57, P60–P67, P70–P77			-10	mA
IOH(avg)	High-level average output current P10-P17, P20-P27, P55-P57, P60-P67, P70-P77			-5	mA
IOL(peak)	Low-level peak output current P10–P17, P20–P27, P51–P53, P55–P57, P70–P77			10	mA
IOL(peak)	Low-level peak output current P40–P47, P60–P67			20	mA
IOL(avg)	Low-level average output current P10–P17, P20–P27, P51–P53, P55–P57, P70–P77			5	mA
IOL(avg)	Low-level average output current P40–P47, P60–P67			15	mA
f(XIN)	External clock input frequency (Note 1)			20	MHz
f(fsys)	System clock frequency			20	MHz

Notes 1: When using the PLL frequency multiplier, be sure that f(fsys) = 20 MHz or less.

2: Average output current is the average value of an interval of 100 ms.

3: The sum of IOL(peak) must be 110 mA or less, the sum of IOH(peak) must be 80 mA or less.







DC ELECTRICAL CHARACTERISTICS (Vcc = 5 V, Vss = 0 V, Ta = -20 to 85 °C, f(fsys) = 20 MHz)

Symbol	Parameter		Toot	conditions		Limits		Unit
Syllibol	٢	arameter	Test	conditions	Min.	Тур.	Max.	Unit
Vон	High-level output voltag	P10-P17, P20-P27, P40-P47, P51-P53, P55-P57, P60-P67, P70-P77, P80-P83	Iон = −10 mA		3			V
Vol	Low-level output voltag	e P10–P17, P20–P27, P40–P47, P51–P53, P55–P57, P60–P67, P70–P77, P80–P83	IOL = 10 mA				2	V
VT+ —VT-	TB0IN-TE CTS2, CL	9in, TA0out-TA9out, 32in, İNT0-İNT7, CTS0, CTS1, .Ko, CLK1, CLK2, RxD0, RxD1, PTRG0, RTPTRG1, P4OUTCUT, JT			0.4		1	V
VT+ —VT-	Hysteresis RESET				0.5		1.5	V
VT+ —VT-	Hysteresis XIN				0.1		0.3	V
ІІН		P10-P17, P20-P27, P40-P47, P51-P53, P55-P57, P60-P67, P70-P77, P80-P83, P4OUTCUT, P6OUTCUT, XIN, RESET, MD0, MD1	Vi = 5.0 V				5	μΑ
IIL	·	P10-P17, P20-P27, P40-P47, P51-P53, P55-P57, P60-P67, P70-P77, P80-P83, P40UTCUT, P60UTCUT, XIN, RESET, MD0, MD1	Vi = 0 V				- 5	μΑ
VRAM	RAM hold voltage		When clock is s	stoped.	2			V
Icc	Power source current		Output-only pins are open, and the other pins are con- nected to Vss or	CPU is active.		25	50	mA
			Vcc. An external square-waveform clock is input. (Pin Χουτ is open.) The	clock is inactive.			1	μΑ
			PLL frequency multiplier is inac- tive.				20	





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A-D CONVERTER CHARACTERISTICS

(Vcc = AVcc = 5 V \pm 0.5 V, Vss = AVss = 0 V, Ta = -20 to 85 °C, unless otherwise noted)

Symbol	Б	T			Limits		
	Parameter Test conditions		Min.	Тур.	Max.	Unit	
	Resolution	VREF = VCC	A-D converter			10	Bits
			Comparator			1 256 VREF	V
			10-bit resolution mode			± 3	LSB
	Absolute accuracy	VREF = VCC	8-bit resolution mode			± 2	LSB
			Comparater			± 40	mV
RLADDER	Ladder resistance	VREF = VCC		5			kΩ
			10-bit resolution mode	5.9			
tCONV	Conversion time	f(fsys) ≤ 20 MHz	8-bit resolution mode	2.45 (Note)			μs
			Comparater	0.7 (Note)			
VREF	Reference voltage		•	2.7		Vcc	٧
VIA	Analog input voltage			0		VREF	V

Note: This is applied when A-D conversion freguency $(\phi AD) = f1 (\phi)$.

D-A CONVERTER CHARACTERISTICS

(VCC = 5 V, VSS = AVSS = 0 V, VREF = 5 V, Ta = -20 to 85 °C, unless otherwise noted)

Symbol	Parameter	Table and Property		1.120		
		Test conditions	Min.	Тур.	Max.	Unit
	Resolution				8	Bits
	Absolute accuracy				± 1.0	%
tsu	Set time				3	μs
Ro	Output resistance		2	3.5	4.5	kΩ
IVREF	Reference power source input current	(Note)			3.2	mA

Note: The test conditions are as follows:

- One D-A converter is used.
- The D-A register value of the unused D-A converter is "0016."
- The reference power source input current for the ladder resistance of the A-D converter is excluded.

RESET INPUT

Reset input timing requirements (Vcc = 5 V \pm 0.5 V, Vss = 0V, Ta = -20 to 85 °C, unless otherwise noted)

Symbol	Danasadan		Limits		11.2
	Parameter	Min.	Тур.	Max.	Unit
tw(RESETL)	RESET input low-level pulse width	10			μs





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PERIPHERAL DEVICE INPUT/OUTPUT TIMING

(Vcc = 5 V±0.5 V, Vss = 0 V, Ta = -20 to 85 °C, f(fsys) = 20 MHz unless otherwise noted)

* For limits depending on f(fsys), their calculation formulas are shown below. Also, the values at f(fsys) = 20 MHz are shown in ().

Timer A input (Count input in event counter mode)

Symbol	Para materia		Limits		
	Parameter	Min.	Max.	Unit	
tc(TA)	TAilN input cycle time	80		ns	
tw(TAH)	TAil input high-level pulse width	40		ns	
tw(TAL)	TAin input low-level pulse width	40		ns	

Timer A input (Gating input in timer mode)

Cymahal	Doromotor		Lin	Linit	
Symbol	Parameter	Parameter		Max.	Unit
tc(TA)	TAil input cycle time	f(fsys) ≤ 20 MHz	$\frac{16 \times 10^9}{\text{f(fsys)}} (800)$		ns
tw(TAH)	TAin input high-level pulse width	f(fsys) ≤ 20 MHz	$\frac{8 \times 10^9}{\text{f(fsys)}} (400)$		ns
tw(TAL)	TAilN input low-level pulse width	f(fsys) ≤ 20 MHz	$\frac{8 \times 10^9}{\text{f(fsys)}} (400)$		ns

Note : The TAilN input cycle time requires 4 or more cycles of a count source. The TAilN input high-level pulse width and the TAilN input low-level pulse width respectively require 2 or more cycles of a count source. The limits in this table are applied when the count source = f2 at f(fsys) ≤ 20 MHz.

Timer A input (External trigger input in one-shot pulse mode)

O and al	Demonster.		Lin	11.2	
Symbol	Parameter	Parameter		Max.	Unit
tc(TA)	TAilN input cycle time	f(fsys) ≤ 20 MHz	$\frac{8 \times 10^9}{\text{f(fsys)}} (400)$		ns
tw(TAH)	TAilN input high-level pulse width		80		ns
tw(TAL)	TAilN input low-level pulse width		80		ns

Timer A input (External trigger input in pulse width modulation mode)

O make al	Parameter		Limits		
Symbol			Max.	Unit	
tw(TAH)	TAilN input high-level pulse width	80		ns	
tw(TAL)	TAin input low-level pulse width	TAim input low-level pulse width 80			

Timer A input (Up-down input and Count input in event counter mode)

		Lim	T	
Symbol	Parameter	Min.	Min. Max.	Unit
tc(UP)	TAiout input cycle time	2000		ns
tw(UPH)	TAiout input high-level pulse width	1000		ns
tw(UPL)	TAiout input low-level pulse width	1000		ns
tsu(UP-TIN)	TAiouT input setup time	400		ns
th(TIN-UP)	TAiout input hold time	400		ns



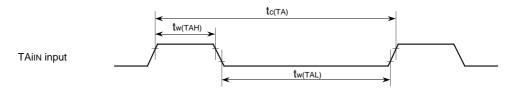


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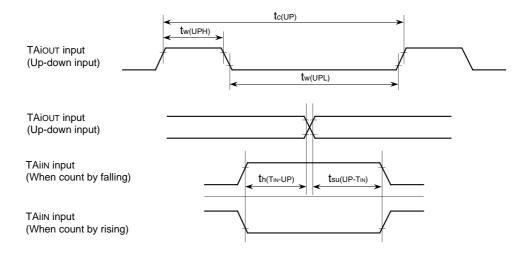
Timer A input (Two-phase pulse input in event counter mode)

Complete	Parameter		Limits		
Symbol			Max.	Unit	
tc(TA)	TAjın input cycle time	800		ns	
tsu(ТАjın-ТАjоuт)	TAjın input setup time	200		ns	
tsu(TAjout-TAjin)	TAjout input setup time	200		ns	

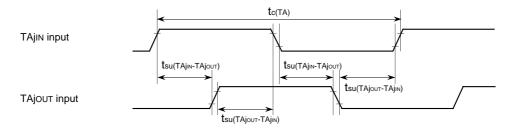
- Gating input in timer mode
- Count input in event counter mode
- External trigger input in one-shot pulse mode
- External trigger input in pulse width modulation mode



• Up-down and Count input in event counter mode



• Two-phase pulse input in event counter mode



Test conditions

- Vcc = $5 V \pm 0.5 V$, Ta = $-20 \text{ to } 85 \text{ }^{\circ}\text{C}$
- Input timing voltage: VIL = 1.0 V, VIH = 4.0 V

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Timer B input (Count input in event counter mode)

Symbol	Parameter	Lin	1.120			
		Min.	Max.	Unit		
tc(TB)	TBilN input cycle time (one edge count) 80					
tw(TBH)	TBilN input high-level pulse width (one edge count) 40					
tw(TBL)	TBilN input low-level pulse width (one edge count) 40					
tc(TB)	TBilN input cycle time (both edge count) 160					
tw(TBH)	TBiln input high-level pulse width (both edge count)	80		ns		
tw(TBL)	TBiln input low-level pulse width (both edge count)	80		ns		

Timer B input (Pulse period measurement mode)

Courada a l	Deservator		Lin	nits	l lait
Symbol	Parameter		Min.	Max.	Unit
tc(TB)	TBilN input cycle time	f(fsys) ≤ 20 MHz	$\frac{16 \times 10^9}{\text{f(fsys)}} (800)$		ns
tw(TBH)	TBilN input high-level pulse width	f(fsys) ≤ 20 MHz	$\frac{8 \times 10^9}{\text{f(fsys)}} (400)$		ns
tw(TBL)	TBilN input low-level pulse width	f(fsys) ≤ 20 MHz	$\frac{8 \times 10^9}{\text{f(fsys)}} (400)$		ns

Note: The TBiIN input cycle time requires 4 or more cycles of a count source. The TBiIN input high-level pulse width and the TBiIN input low-level pulse width respectively require 2 or more cycles of a count source. The limits in this table are applied when the count source = f2 at f(fsys) ≤ 20 MHz.

Timer B input (Pulse width measurement mode)

Coursels al	Description	Limits		nits	l lait
Symbol	Parameter		Min.	Max.	Unit
tc(TB)	TBilN input cycle time	f(fsys) ≤ 20 MHz	$\frac{16 \times 10^9}{\text{f(fsys)}} (800)$		ns
tw(TBH)	TBilN input high-level pulse width	f(fsys) ≤ 20 MHz	$\frac{8\times10^9}{\text{f(fsys)}} (400)$		ns
tw(TBL)	TBilN input low-level pulse width	f(fsys) ≤ 20 MHz	$\frac{8 \times 10^9}{\text{f(fsys)}} (400)$		ns

Note: The TBiIN input cycle time requires 4 or more cycles of a count source. The TBiIN input high-level pulse width and the TBiIN input low-level pulse width respectively require 2 or more cycles of a count source. The limits in this table are applied when the count source = f2 at f(fsys) ≤ 20 MHz.

Serial I/O

	Parameter	Lin			
Symbol		Min.	Max.	Unit	
tc(CK)	CLKi input cycle time	CLKi input cycle time 200			
tw(CKH)	CLKi input high-level pulse width	100		ns	
tw(CKL)	CLKi input low-level pulse width	100		ns	
td(C-Q)	TxDi output delay time		80	ns	
th(C-Q)	TxDi hold time	0		ns	
tsu(D-C)	RxDi input setup time	20		ns	
th(C-D)	RxDi input hold time	90		ns	

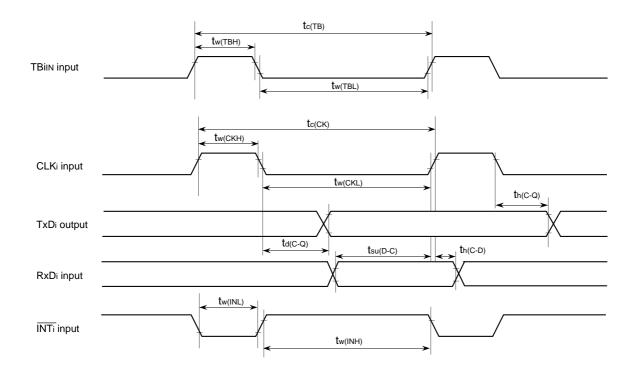






External interrupt (INTi) input

Completed	Parameter		Limits	
Symbol			Max.	Unit
tw(INH)	INTi input high-level pulse width	250		ns
tw(INL)	INTi input low-level pulse width	250		ns



Test conditions

 \bullet Vcc = 5 V \pm 0.5 V, Ta = –20 to 85 $^{\circ}C$

• Input timing voltage : VIL = 1.0 V, VIH = 4.0 V

• Output timing voltage : VoL = 0.8 V, VoH = 2.0 V, CL = 50 pF



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External clock input

Timing Requirements (VCC = 5 V \pm 0.5 V, Vss = 0 V, Ta = -20 to 85 °C, unless otherwise noted)

C:h al	Davamatan	Limi	nits	l lait	
Symbol	Parameter	Min.	Max.	Unit	
tc	External clock input cycle time	50		ns	
tw(half)	External clock input pulse width with half input-voltage	0.45 tc	0.55 tc	ns	
tw(H)	External clock input high-level pulse width	0.5 tc - 8		ns	
tw(L)	External clock input low-level pulse width	0.5 tc - 8		ns	
tr	External clock input rise time		8	ns	
tf	External clock input fall time		8	ns	

External clock input

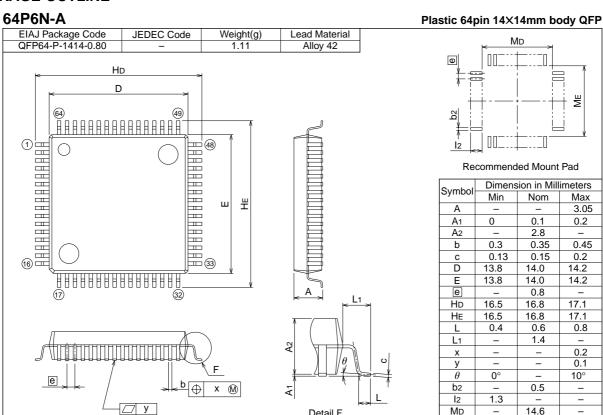


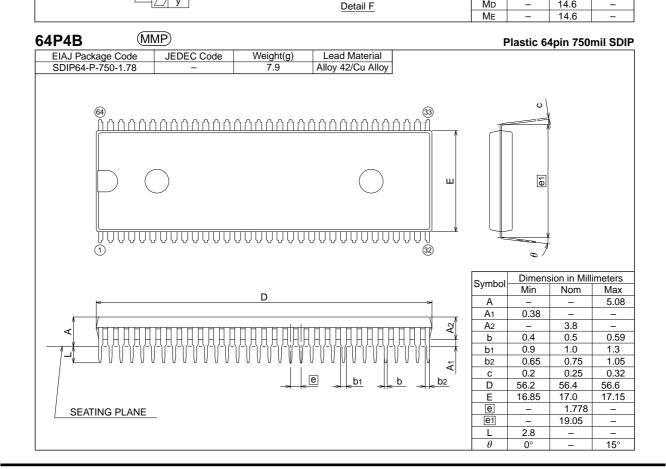
Test conditions

- Vcc = 5 V \pm 0.5 V, Ta = -20 to 85 °C Input timing voltage : VIL = 1.0 V, VIH = 4.0 V ($t_{w(H)}$, $t_{w(L)}$, t_r , t_f)
- Output timing voltage : 2.5 V (tc, tw(half))



PACKAGE OUTLINE









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Renesas Technology Corp.

Nippon Bldg., 6-2, Otemachi 2-chome, Chiyoda-ku, Tokyo, 100-0004 Japan

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